



74AHC594

8-BIT SHIFT REGISTER WITH 8-BIT OUTPUT REGISTER

Description

The 74AHC594 is an advanced high speed CMOS device.

An eight bit shift register accepts data from the serial input (DS) on each positive transition of the shift register clock (SHCP). When asserted low the shift register reset function (\overline{SHR}) sets all shift register values to zero and is independent of all clocks. Also when asserted low the storage register reset function (\overline{STR}) sets all shift register values to zero and is independent of all clocks.

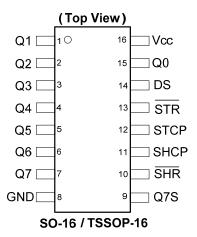
Data from the input serial shift register is placed in the output register with a rising pulse on the storages resister clock (STCP). The storage resister includes output Q7S which is used for cascading information between devices. As the information moves into the storage register, it is asserted on the push-pull outputs Q0-Q7.

All registers capture data on rising edge and change output on the falling edge. If both clocks are connected together, the input shift register is always one clock cycle ahead of the output register.

Features

- Wide Supply Voltage Range from 2.0V to 5.5V
- Sinks or sources 8mA at V_{CC} = 4.5V
- CMOS low power consumption
- Schmitt Trigger Action at All Inputs
- Inputs accept up to 5.5V
- ESD Protection Tested per JESD 22
 - Exceeds 200-V Machine Model (A115-A)
 Exceeds 2000-V Human Body Model (A114-A)
 - Exceeds 2000 V Hamail Body Model (VVIII)
 - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 250mA per JESD 78, Class II
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



Applications

- General Purpose Logic
- Serial to Parallel Data conversion
- Capture and hold data for extended periods of time.
- Allow simple serial bit streams from a microcontroller to control as many peripheral lines as needed
- · Wide array of products such as:
 - Computer Peripherals
 - Appliances
 - Industrial Control

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

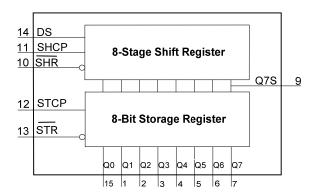
Click here for ordering information, located at the end of datasheet



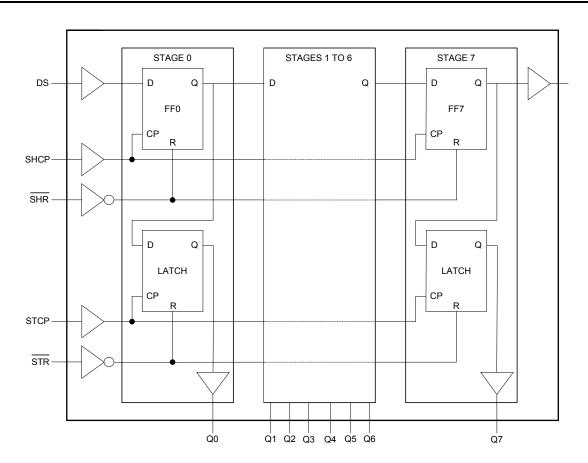
Pin Descriptions

Pin Number	Pin Name	Functions
1	Q1	Parallel Data Output 1
2	Q2	Parallel Data Output 2
3	Q3	Parallel Data Output 3
4	Q4	Parallel Data Output 4
5	Q5	Parallel Data Output 5
6	Q6	Parallel Data Output 6
7	Q7	Parallel Data Output 7
8	GND	Ground
9	Q7S	Serial Data Output
10	SHR	Shift Register Reset active low
11	SHCP	Shift Register Clock Input
12	STCP	Storage Register Clock Input
13	STR	Storage Register Reset active low
14	DS	Serial Data input
15	Q0	Parallel Data Output 0
16	Vcc	Supply Voltage

Functional Diagram



Logic Diagram

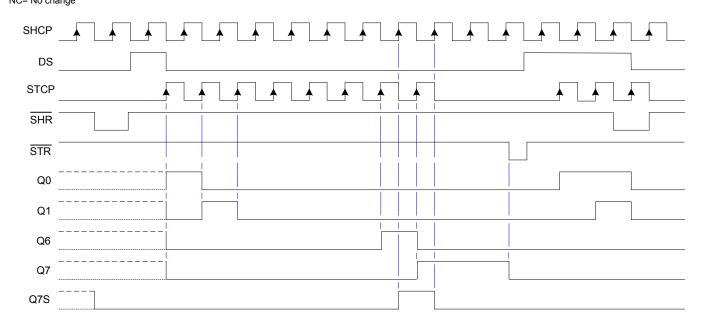




Functional Description and Timing Diagram

	Control			Input	Ot	utput	Forestive
SHR	STR	SHCP	STCP	DS	Q7S	Qn	Function
L	Х	Х	Х	Х	L	NC	Clear Shift Register
Х	L	Х	Х	Х	NC	L	Clear Storage Register
Н	Х	1	L	H or L	Q6S	NC	Loads DS into shift register stage 0. All Q _S shifted
Н	Н	Х	1	Х	NC	Qs Contents of shift register moved to starge register all Q _S -> Q ₁	
Н	Н	1	1	H or L	Q6S	QnS	Shift Register one pulse count ahead of storage register.

H=HIGH voltage state L=LOW voltage state ↑=LOW to HIGH transition X= don't care – high or low (not floating) NC= No change



Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	V
V_{CC}	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range	-0.5 to +7.0	V
Vo	Voltage applied to output in high or low state	-0.3 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current V _I < -0.5V	-20	mA
lok	Output Clamp Current Vo<-0.5V	-20	mA
I _{OK}	Output Clamp Current Vo> Vcc +0.5V	20	mA
Io	Continuous output current	±25	mA
Icc	Continuous current through Vcc	75	mA
I _{GND}	Continuous current through GND	-75	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
P _{TOT}	Total Power Dissipation	500	mW

Notes: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Recommended Operating Conditions (Note 5) (@TA = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
Vcc	Supply Voltage	_	2.0	5.5	V
VI	Input Voltage	-	0	5.5	V
Vo	Output Voltage	_	0	V _{CC}	V
Δt/ΔV	Input transition Rise or Fall Rate	V _{CC} = 3.0V to 3.6V	-	100	20/1
ΔυΔν	Imput transition Rise of Fall Rate	V _{CC} = 4.5V to 5.5V	-	20	ns/V
TA	Operating Free-Air Temperature	-	-40	+125	°C

Note:

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions	V	TA	= +25°	С	$T_A = -40$ °C	to +85°C	$T_A = -40^{\circ}$	C to +125°C	Unit
Syllibol	Parameter	rest Conditions	V _{CC}	Min	Тур	Max	Min	Max	Min	Max	Unit
		=	2.0V	1.5	_	_	1.5	-	1.5	-	
V_{IH}	High-Level Input Voltage	_	3.0V	2.1	_	_	2.1	-	2.1	-	V
	mpat voltago	=	5.5V	3.85	-	_	3.85	-	3.85	=	
		-	2.0V	_	_	0.5	-	0.5	_	0.5	
V_{IL}	Low-Level Input Voltage	_	3.0V	_	_	0.9	-	0.9	_	0.9	V
	input voltage	=	5.5V	_	_	1.65	-	1.65	-	1.65	
		$I_{OH} = -50 \mu A$	2.0V	1.9	2.0	_	1.9	-	1.9	-	
	V _{OH} High-Level Output Voltage	I _{OH} = -50μA	3.0V	2.9	3.0	_	2.9	-	2.9	-	
V_{OH}		I _{OH} = -50μA	4.5V	4.4	4.5	_	4.4	=	4.4	=	V
		I _{OH} = -4mA	3.0V	2.58	_	_	2.48	-	2.40	-	
		I _{OH} = -8mA	4.5V	3.94	_	_	3.80	-	3.70	-	
		I _{OL} = 50μA	2.0V	_	0	0.1	_	0.1	-	0.1	
		I _{OL} = 50μA	3.0V	_	0	0.1	=	0.1	=	0.1	
V_{OL}	Low-Level Output Voltage	I _{OL} = 50μA	4.5V	_	0	0.1	=	0.1	=	0.1	V
	Output Voltage	I _{OL} = 4mA	3.0V	_	-	0.36	=	0.44	=	0.55	
		I _{OL} = 8mA	4.5V	_	_	0.36	=	0.44	=	0.55	
I _I	Input Current	V _I = GND or 5.5V	5.5V	_	0.01	± 0.1	-	± 1	-	± 2	μΑ
I _{CC}	Supply Current	$V_I = GND \text{ or } V_{CC}$ $I_O = 0$	5.5V	-	=	4	-	40	-	80	μΑ
Ci	Input Capacitance	V _i = V _{CC} or GND	5.5V	=	3.5	10	=	10	=	10	pF

^{5.} Unused inputs should be held at V_{CC} or Ground.



Switching Characteristics

Symbol /	Pins	Test Conditions	V	Т	A = +25°	С	-40°C to	o +85°C	-40°C to	+125°C	Unit		
Parameter	Pins	rest Conditions	V _{CC}	Min	Тур	Max	Min	Max	Min	Max	Unit		
f _{MAX}	SHCP or		3.0V to 3.6V	80	125	-	70	-	65	_			
Maximum Frequency	STCP	Figure1	4.5V to 5.5V	90	70	_	80	-	70	-	MHz		
	SHCP and		3.0V to 3.6V	6.0	_	-	6.5	-	7.0	_			
tw	STCP HIGH or LOW	Figure1	4.5V to 5.5V	5.5	=	-	6.0	=	6.5	-	ns		
Pulse Width	SHR and STR	Figure1	3.0V to 3.6V	5.0	-	-	5.0	=	5.5	_			
	HIGH or LOW	rigulei	4.5V to 5.5V	5.0	_	-	5.2	-	5.7	_			
	DS to SHCP	Figure1	3.0V to 3.6V	3.5	_	-	3.5	=	3.5	_	ns		
	D3 t0 311CF	rigulei	4.5V to 5.5V	3.0	-	-	3.0	=	3.0	_	115		
t _{SU}	CUD to CTCD	Figure1	3.0V to 3.6V	8.0	-	-	9.0	=	9.5	_			
Set-up Time	SHR to STCP	rigurer	4.5V to 5.5V	5.0	_	-	5.0	-	5.5	_			
	SHCP tp	Figure1	3.0V to 3.6V	8.0	_	-	8.5	-	9.0	_	ns		
	STCP	rigule	4.5V to 5.5V	5.0	_	-	5.0	=	5.5	_	113		
t _H	DS to SHCP	Figure1	3.0V to 3.6V	1.5	-	-	1.5	=	1.5	_			
Hold Time	D3 t0 311CF	rigulei	4.5V to 5.5V	2.0	_	-	2.0	-	2.0	_	ns		
	CUD to CUCD	Figure1	3.0V to 3.6V	4.2	_	-	4.8	-	5.3	_	ns		
t _{REC}	SHR to SHCP	SHR to SHCP	SHR to SHCP	rigulei	4.5V to 5.5V	2.9	_	-	3.3	-	3.8	_	115
Recovery Time	SHR to STCP	Figure1	3.0V to 3.6V	4.6	_	-	5.3	=	5.8	_	ns		
	SHR to STCP	rigulei	4.5V to 5.5V	3.2	-	-	3.7	=	4.3	_	115		
		Figure1 C _L = 15pF	3.0V to 3.6V	-	5.2	8.5	2.2	9.7	2.2	10.6			
	SHCP toQ7S	rigure i CL = 15pr	4.5V to 5.5V	-	3.8	6.3	1.7	7.2	1.7	7.8	ns		
t _{PLH}	SHOP LOGIS	Figure1 C _L = 50pF	3.0V to 3.6V	-	7.4	11.5	3.0	13.2	3.0	14.3	115		
OW to HIGH		rigure i CL = 50pr	4.5V to 5.5V	-	4.8	8.0	2.4	9.1	2.4	10.0			
Propagation		Figure1 C _L = 15pF	3.0V to 3.6V	_	5.1	8.3	2.3	9.5	2.3	10.6			
Delay	STCP to Qn	rigure i CL = 15pF	4.5V to 5.5V	-	3.5	5.7	1.8	6.5	1.8	7.1			
	310F 10 Q11	Figure1 C _L = 50pF	3.0V to 3.6V	-	7.3	11.9	3.3	13.6	3.3	14.7	ns		
		Figure 1 CL = 50pF	4.5V to 5.5V	_	4.8	7.8	2.6	9.0	2.6	9.8			



Switching Characteristics (cont.)

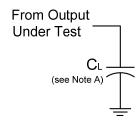
Symbol /	Pins	Test Conditions	V	Т	A = +25°	С	-40°C°C	to +85°C	-40°C°C 1	o +125°C	Unit
Parameter	Pilis	rest Conditions	V _{CC}	Min	Тур	Max	Min	Max	Min	Max	Unit
		Figure 4.0. – 45°F	3.0V to 3.6V	_	5.5	8.9	2.3	10.2	2.3	11.0	
	SHCP toQ7S	Figure 1 C _L = 15pF	4.5V to 5.5V	_	4.1	6.7	1.9	7.6	1.9	8.2	ns
	3HCP 10Q/3	F: 10 F0 F	3.0V to 3.6V	_	7.4	12.1	3.0	13.9	3.0	15.1	
		Figure 1 C _L = 50pF	4.5V to 5.5V	_	5.4	8.8	2.5	10.1	2.5	11.0	
		Figure 1 C = 15pF	3.0V to 3.6V	_	5.5	9.1	2.4	10.4	2.4	11.3	
	STCP to Qn	Figure 1 C _L = 15pF	4.5V to 5.5V	_	3.7	6.0	1.9	6.9	1.9	7.5	no
tрнLн	STOP LO QII	Figure 1 C = F0×F	3.0V to 3.6V	_	7.3	12.0	3.2	13.8	3.2	15.0	ns
HIGH to LOW		Figure 1 C _L = 50pF	4.5V to 5.5V	_	5.2	8.5	2.6	9.7	2.6	10.5	
Propagation		Figure 1 C. = 1FpF	3.0V to 3.6V	-	5.7	9.5	2.3	10.8	2.3	11.7	
Delay	SHR to	Figure 1 C _L = 15pF	4.5V to 5.5V	-	4.1	6.7	2.0	7.6	2.0	8.2	ns
	Q7S	Figure 1 C _L = 50pF	3.0V to 3.6V	_	7.5	12.2	3.6	14.0	3.6	15.2	115
			4.5V to 5.5V	_	5.4	8.8	2.8	10.1	2.8	11.0	
			3.0V to 3.6V	-	4.1	7.2	2.2	8.2	2.2	8.9	ns
	STR		4.5V to 5.5V	-	4.1	7.2	2.2	8.2	2.2	8.9	
	to Qn		3.0V to 3.6V	-	5.4	9.4	3.0	10.7	3.0	11.6	
		rigule 1 CL = 50pr	4.5V to 5.5V	-	5.4	9.4	3.0	10.7	3.0	11.6	
			2.0V	-	39	150	=	185	-	225	
	CUD to 070	Figure 1	4.5V	-	14	30	_	37	_	45	ns
	SHR to Q7S		5.0V	-	11	_	_	-	_	-	
t _{PHL}			6.0V	-	12	26	_	31	_	38	
Propagation Delay			2.0V	-	39	125	_	155	_	185	
20.0,	STR to Qn	Figure 1	4.5V	-	14	25	=	31	_	37	ns
	SIR to Qn		5.0V	-	11	_	_	-	_	-	115
			6.0V	-	12	21	_	26	_	31	
	0 :	Figure 4	2.0V	-	19	75	_	95	_	110	
Out	Serial data output Q7S	Figure 1	4.5V	_	7	15	-	19	_	22	ns
t _{THL} Transition			6.0V	-	6	13	-	16	_	19	
Time	Parallel Data	Figure 1	2.0V	=	14	60	=	75	=	90	
	Outputs Q _N	rigule i	4.5V	-	5	12	-	15	_	18	ns
			6.0V	-	4	10	-	13	_	15	

Operating Characteristics (@T_A = +25°C, unless otherwise specified.)

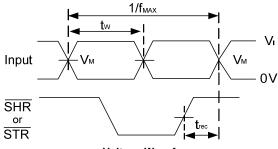
	Parameter	Test	V _{CC} = 5V	Unit
Parameter		Conditions	Тур	Onne
$C_{\sf pd}$	Power dissipation capacitance	f = 1 MHz all outputs switching-no load	51	pF



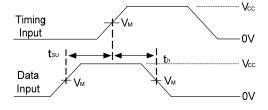
Parameter Measurement Information



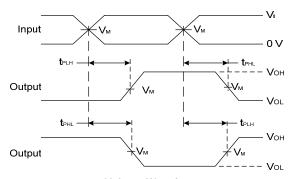
.,	In	puts	
V _{CC}	VI	t _r /t _f	V _M
4.5V	Vcc	6ns	V _{CC} /2
5.0V	V _{CC}	6ns	V _{CC} /2



Voltage Waveform Pulse Duration and Recovery Time



Voltage Waveform Set-up and Hold Times



Voltage Waveform Propagation Delay Times **Inverting and Non Inverting Outputs**

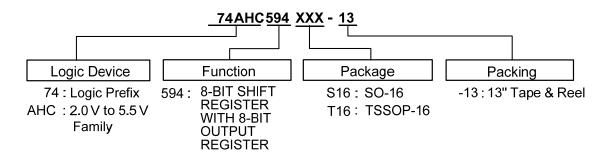
Notes:

- A. Includes test lead and test apparatus capacitance.B. All pulses are supplied at pulse repetition rate ≤ 10MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{PD} .

Figure 1 Load Circuit and Voltage Waveforms



Ordering Information

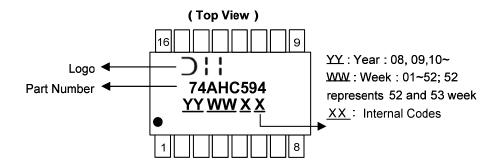


Part Number	Bookaga Cada	Dockoning	7" Tape and	Reel (Note 6)
Part Number	Package Code	Packaging	Quantity	Part Number Suffix
74AHC594S16-13	S16	SO-16	2500/Tape & Reel	-13
74AHC594T16-13	T16	TSSOP-16	2500/Tape & Reel	-13

Note: 6. The taping orientation is located on our website at http://www.diodes.com/datasheets/ap02007.pdf

Marking Information

(1) SO-16, TSSOP16



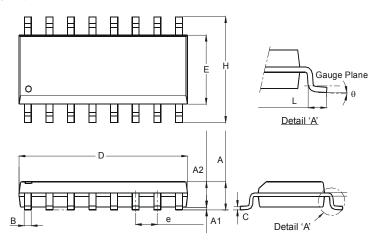
Part Number	Package		
74AHC594S16	SO-16		
74AHC594T16	TSSOP-16		



Package Outline Dimensions (All dimensions in mm.)

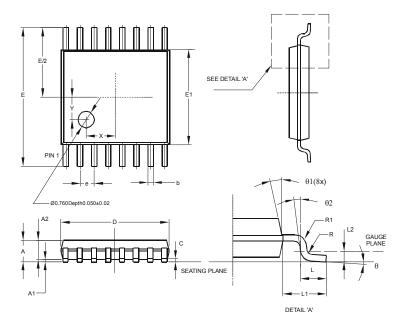
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Package Type: SO-16



	SO-16					
Dim	Min	Max				
Α	1.40	1.75				
A1	0.10	0.25				
A2	1.30	1.50				
В	0.33	0.51				
С	0.19	0.25				
D	9.80	10.00				
Е	3.80	4.00				
е	1.27	Тур				
H	5.80	6.20				
L	0.38	1.27				
Θ	0°	8°				
All D	All Dimensions in mm					

Package Type: TSSOP-16



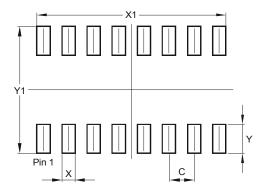
TSSOP-16				
Dim	Min	Max	Тур	
Α	-	1.08	-	
A1	0.05	0.15	-	
A2	0.80	0.93	-	
b	0.19	0.30	-	
C	0.09	0.20	1	
D	4.90	5.10	1	
Е	6.40 BSC			
E1	4.30	4.50	ı	
е	0.65 BSC			
L	0.45	0.75	-	
L1	1.00 REF			
L2	0.25 BSC			
R	0.09	-	-	
R1	0.09	-	-	
Χ	ı	ı	1.350	
Υ	ı	ı	1.050	
Θ	0°	8°	-	
Θ1	5°	15°	-	
Θ2	0°	-	-	
All Dimensions in mm				



Suggested Pad Layout

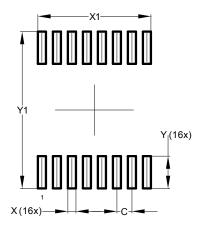
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

Package Type: SO-16



Dimensions	Value (in mm)	
С	1.270	
Х	0.670	
X1	9.560	
Y	1.450	
Y1	6.400	

Package Type: TSSOP-16



Dimensions	Value (in mm)	
С	0.650	
Х	0.350	
X1	4.900	
Y	1.400	
V1	6.800	



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